


Cite this: *RSC Adv.*, 2024, 14, 2320

Effect of sulphidation process on the structure, morphology and optical properties of GO/AgNWs composites

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In this study, composite materials composed of graphene oxide (GO) synthesized by a modified Hummers' method and silver nanowires (AgNWs) synthesized by a modified polyol method were prepared. The prepared composites were subjected to sulfidation under the influence of H₂S gas. Structural changes in the samples were evaluated using X-ray diffraction (XRD). The binding nature of the composite was characterized using FT-IR spectroscopy. Optical properties and band gap values were investigated using ultraviolet-visible (UV-Vis) spectroscopy. The morphology of the composites was analyzed by transmission electron microscopy (TEM). A simple method using H₂S gas was applied for the sulphidation process of the samples. The sulfidation process was successful under the influence of H₂S gas, resulting in an increased distance between the GO layers and a decrease in the band gap value for the composite post-sulfidation. In addition, AgNWs were observed to decompose into Ag₂S nanoparticles under the influence of H₂S gas. It was determined that the value of the band gap of the sample changes because of sulphidation.

Received 23rd November 2023

Accepted 4th January 2024

DOI: 10.1039/d3ra08044g

rsc.li/rsc-advances

1 Introduction

In recent decades, GO and AgNWs have emerged as materials of particular interest due to their unique properties.^{1–5} These materials can be applied in various devices and systems, each exhibiting superior characteristics.^{6–14} However, challenges are associated with these materials. Specifically, AgNWs possess high chemical reactivity and are prone to oxidation, while the abundance of touchpoints in AgNWs leads to a decrease in conductivity. Research indicates that these issues can be addressed by covering these nanowires with graphene oxide (GO) sheets.^{15,16} Furthermore, investigations reveal that GO/AgNWs composites not only mitigate the incompatibilities between individual components but also offer new advantages. Remarkably, GO/AgNWs composites possess properties such as photonic stability, plasmonic resonance, high surface energy, and biocompatibility.¹⁷ The role of 1D AgNWs embedded in GO

layers in enhancing electrical conductivity and mechanical flexibility should be emphasized, as this feature can be employed to create delicate, highly conductive layers, potentially addressing challenges in solar batteries and sensors.¹⁸

Another intriguing aspect of research involves the sulfidation of these samples. Sulfidation can result in the formation of Ag₂S, which transforms the material into a semiconductor with new properties. Research on Ag₂S indicates that it is a non-toxic material, making it suitable for optoelectronic and photocatalytic applications.¹⁹ It is known that Ag readily undergoes sulfidation in an H₂S environment, leading to the formation of Ag₂S, and literature results show that the sulfidation of AgNWs results in the creation of Ag–Ag₂S NWs heterostructures, yielding high photocatalytic properties.^{20–22} The impact of sulfidation on GO has also been extensively investigated, revealing that sulfidated GO sheets undergo crumpling and bending.²³ The influence of sulfur on defects in GO sheets has been observed, with defects increasing in size depending on the sulfur dosage.²⁴ Additionally, sulfur-doped GO is utilized as an electrode material in capacitors due to its high electrical conductivity.^{25,26} Ag₂S/GO nanocomposites can be used as an antibacterial element in terms of photothermal and photocatalytic properties.²⁷ Research shows that Ag₂S/GO nanocomposites exhibit better luminescence properties than Ag₂S.²⁸ Also, these composites can be used for photocatalytic purposes by making various additives.²⁹ Ag₂S and GO samples are used separately in PV materials, so that these materials can be used

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in a composite form, which can create a wide range for PV materials.^{30,31}

In this study, a successful synthesis of GO/AgNWs composites has been achieved, and a simple method has been proposed for sulfidating these composites. The effects of H₂S gas on the properties of GO/AgNWs composites were investigated, and samples were prepared by exposing them to H₂S gas. The structural, morphological, and optical properties of the samples were examined both before and after sulfidation, and a comparative analysis was conducted.

2 Materials and methods

2.1 Synthesis of GO

The investigated work involved the synthesis of GO modified by the Hummers' method.^{32–34} Initially, 3 grams of graphite powder were placed in a 500 ml container, and 1.5 g of sodium nitrate (NaNO₃) was added. Subsequently, 70 ml of concentrated sulfuric acid (H₂SO₄) was added to the sample, and the mixture was cooled to 0 °C in an ice bath. Under these conditions, the mixture was stirred for 1 hour using a magnetic stirrer. Concurrently, potassium permanganate (KMnO₄) was gradually added to the mixture at a slow rate. It is crucial to maintain the reaction temperature below 20 °C by adding KMnO₄ in small increments. After the addition of KMnO₄, the mixture was stirred for 3 hours. Following this, the mixture was removed from the ice bath and stirred for an additional hour at 35 °C. In the next stage, 150 ml of water was added dropwise, and the mixture was stirred at 98 °C for 30 minutes. Subsequently, 300 ml of water was added gradually, and the mixture was stirred for 1 hour. Then, 15 ml of 30% hydrogen peroxide (H₂O₂) was added, and the mixture was stirred for 30 minutes. The resulting mixture was filtered through filter paper, and to remove residual metal ions, it was washed with distilled water (DW) (250 ml) containing hydrochloric acid (HCl) in a 1:10 ratio. Finally, the resulting product was dried at room temperature.

2.2 Synthesis of AgNWs and GO/AgNWs composites

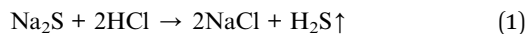
Silver nanowires were synthesized using a modified polyol method inspired by the literature.³⁵ Ethylene glycol (EG) was used as both a solvent and a silver-reducing agent, while polyvinylpyrrolidone (PVP, molecular weight: 360 000) acted as a capping agent. Sodium chloride (NaCl) and potassium bromide (CuBr₂) were used to maintain charge balance and facilitate growth. In a summary of the synthesis process, PVP was dissolved in EG at a concentration of 295.6 mM for 3 hours at an elevated temperature, then cooled down to room temperature. Solutions of CuBr₂ (3.2 mM) and NaCl (15.7 mM) in EG were prepared for later use. Silver nitrate (AgNO₃) was dissolved in EG to reach a concentration of 187.8 mM. The synthesis procedure involved placing 5 ml of EG into a 20 ml vial, which was then heated in a silicone oil bath at 160 °C. CuBr₂ (100 µl) and NaCl (150 µl) solutions were injected into the vial after 10 minutes. Over 15 minutes, 1.5 ml of AgNO₃ and 1.5 ml of PVP solutions were added drop by drop. After the

addition of AgNO₃ and PVP, the reaction continued for 1.5 hours and was cooled down to room temperature. To collect the silver nanowires, acetone was added to the reaction solution, resulting in precipitates. The precipitates were collected after centrifugation at 4000 rpm for 8 minutes. The washing process was repeated three times to remove excess chemicals. The final product was dispersed in ethanol for future use.

In this study, a solvent mixing method was employed to prepare the composite material. Initially, 0.48 g of GO and 0.02 g of AgNWs were mixed in ethanol. Subsequently, the mixture was subjected to ultrasound for 20 minutes to achieve proper dispersion. After ultrasonication, the mixture was filtered and dried at 60 °C. Consequently, composite materials with a 2 wt% concentration of AgNWs in GO (referred to as GO/AgNWs composites) were successfully prepared.

2.3 S doped GO/AgNWs composites

A simple method was used to sulphide the samples. So, first, sodium sulfide (Na₂S) is placed inside the laboratory glass container, and then it is closed with a lid. A small gap is kept for air to escape from the bowl. Then the prepared GO/AgNWs nanocomposites are placed on the filter paper and placed on this gap. In the next step, hydrochloric acid (HCl) is gradually added to the container drop by drop using a pipette. During this process, the following reaction (1) occurs:



With the addition of HCl, H₂S gas is formed inside the vessel. The gas escapes into the air through the cavity where the sample is placed. At this time, the sample is exposed to H₂S gas, and the sample is sulphided. Note that the whole process was carried out at room temperature. A description of the sulphidation process is given in Fig. 1.

2.4 Characterization

The structural analysis of the samples was studied using the Rigaku Mini Flex 600 X-ray diffractometer ($\lambda = 1.5406 \text{ \AA}$) using Ni-filtered Cu K α radiation. Fourier Transform Infrared (FT-IR) spectra were recorded on a Bruker-vertex80 spectrophotometer in KBr pellets. The optical properties of the samples were

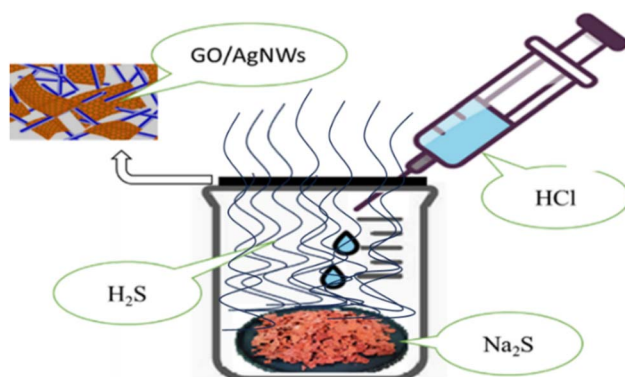


Fig. 1 Doping process of GO/AgNWs with H₂S.

investigated using a PerkinElmer Lambda 2S UV-Vis Spectrophotometer in the wavelength range of 190–1100 nm. The morphology of the samples was studied by JEM 1400 (JEOL, Japan).

3 Result and discussion

3.1 X-ray diffraction analysis

XRD diffractograms for GO, GO/AgNWs and GO/AgNWs + H₂S samples are shown in Fig. 1. Fig. 2a demonstrates the structural properties for a sample of GO. The observed peaks at $2\theta = 11.09^\circ$ and 42.06° are characteristic of GO (JCPDS card #75-2078) and indicate the successful synthesis process. The interplanar distance for GO was determined to be $d = 0.80$ nm. Also, the peak observed at $2\theta = 26.24^\circ$ corresponds to residual graphite during the reaction.³⁶

$$d_{h,k,l} = \frac{n\lambda}{2 \sin \theta} \quad (2)$$

XRD spectra for GO/AgNWs nanocomposites are shown in Fig. 2b. The peaks at $2\theta = 11.09^\circ$, 26.24° , 42.06° belong to GO, the first element of the composite. Peaks corresponding to (111), (200), (220) and (311) planes observed at $2\theta = 38.33^\circ$, 44.51° , 64.63° and 77.58° are characteristic of AgNWs (JCPDS card no. 04-0783).³⁷ The interplanar distance for GO sheets within the composite increased to $d = 0.82$ nm. This can be attributed to the inclusion of AgNWs between the GO sheets.

XRD spectra of GO/AgNWs composites exposed to H₂S gas are shown in Fig. 3c. Comparing with the initial spectrum of the composite, the characteristic peaks for AgNWs disappeared and new peaks appeared at 28.92° , 32.34° and 57.59° . These peaks are characteristic of Ag₂S (JCPDS card no. 14-0072) and indicate that the samples were successfully sulfidized by exposure to H₂S gas. However, a small peak with (311) index, characteristic of AgNWs, is still observed. This indicates that the AgNWs are not fully sulphided and formed as Ag–Ag₂S heterostructure. Interplanar distance for GO was calculated and found to increase to $d = 0.84$ nm after sulphidation process. This can be attributed

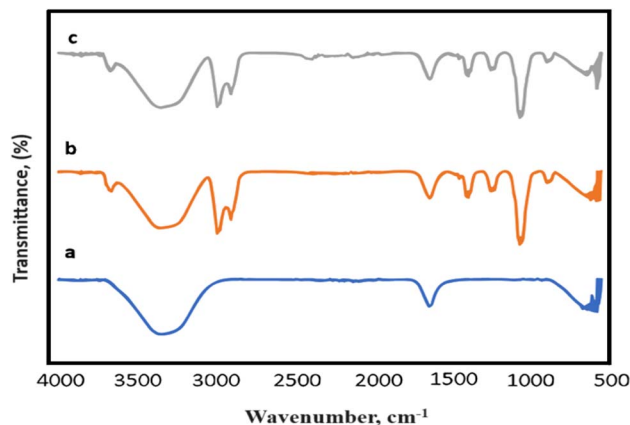


Fig. 3 FT-IR spectra of (a) GO, (b) GO/AgNWs, (c) GO/AgNWs + H₂S samples.

to the fact that the AgNWs inserted between the GO layers are decomposed under the influence of H₂S gas and increase the surface area by forming Ag₂S.

3.2 FTIR analysis

The FTIR results of the samples before and after the doping process are presented in Fig. 3. Fig. 3a–c display the IR spectrum of GO, GO/AgNWs, and S-doped GO/AgNWs composites, respectively. In the spectrum of GO, the broad absorption peak observed at 3369 cm^{-1} corresponds to the OH stretching vibration. The peaks at 1631 cm^{-1} and 599 cm^{-1} are ascribed to the C=C stretching and OH out-of-plane bend, respectively.^{38,39} In the spectrum of GO/AgNWs composite, the peaks at 2985 cm^{-1} and 2874 cm^{-1} are attributed to the asymmetric and symmetric stretching vibrations of CH₂, respectively. The peaks observed at 1417 cm^{-1} and 1385 cm^{-1} are related to the CH deformation modes from the CH₂ group. In addition, the absorption bands at 1247 cm^{-1} and 1040 cm^{-1} are correspond to C–N bending and stretching vibrations from the pyrrolidone structure, respectively.⁴⁰ The peak at 883 cm^{-1} is attributed to the breathing vibration of the pyrrolidone ring, indicating the tilting of the pyrrolidone ring on the surface of AgNWs.⁴¹ In the spectrum of sulfur doped composite (Fig. 3c), the new weak peak was appeared at 2367 cm^{-1} and it indicates the presence of Ag–S bonds of formed Ag₂S.^{42,43} This newly formed bond provides evidence of the successful doping of the composite with sulfur.

3.3 UV-Vis spectroscopy analysis

Fig. 4 presents the UV-Vis absorption spectra and $(\alpha h\nu)^2$ versus $h\nu$ curves for the samples. In Fig. 4A, a minor absorption peak is evident at 220 nm, indicative of graphene oxide and associated with the π – π^* transition of C–C bonds.⁴⁴ Furthermore, Fig. 4A illustrates the optical absorption spectrum of silver nanowires (AgNWs), exhibiting characteristic peaks at 353 nm and 390 nm, corresponding to the surface plasmon resonances of AgNWs.⁴⁵ The introduction of AgNWs amplifies the composite's optical absorption due to the pronounced absorption properties of

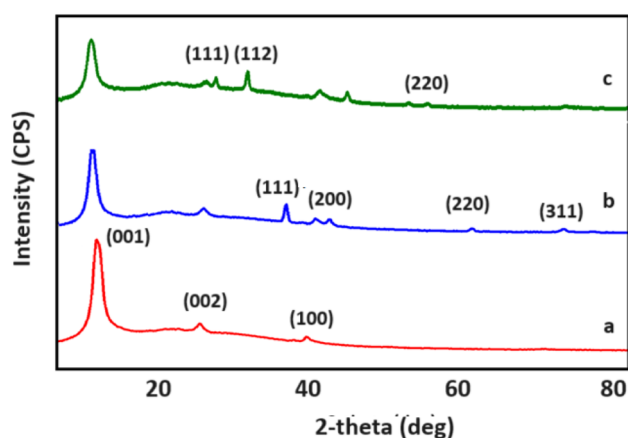


Fig. 2 Diffractograms of (a) GO, (b) GO/AgNWs, (c) GO/AgNWs + H₂S samples.



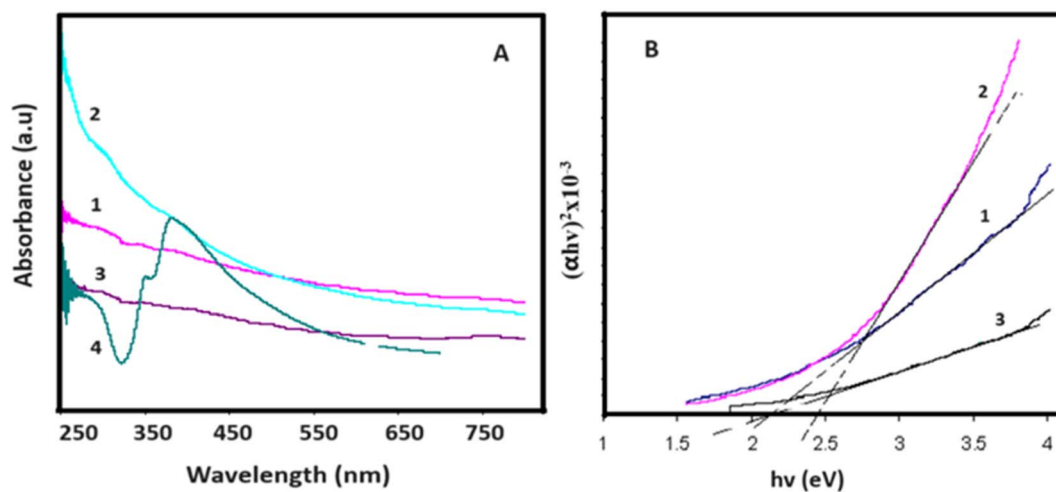


Fig. 4 (A) UV-Vis absorption spectra and (B) $(\alpha h\nu)^2$ versus $h\nu$ curves for 1-GO, 2- GO/AgNWs, 3- GO/AgNWs + H₂S and 4-AgNWs.

AgNWs. However, a reduction in optical absorption is noted following sulfur (S) doping. This decline is attributed to the sulfidation of AgNWs and alterations in the surface properties of the composite.

The band gap values for the samples were determined through the Tauc plot (2), and the $(\alpha h\nu)^2$ versus $h\nu$ curves are depicted in Fig. 4B. As illustrated in Fig. 4B, graphene oxide powder exhibits a band gap value of $E_g = 2.10$ eV. In the case of

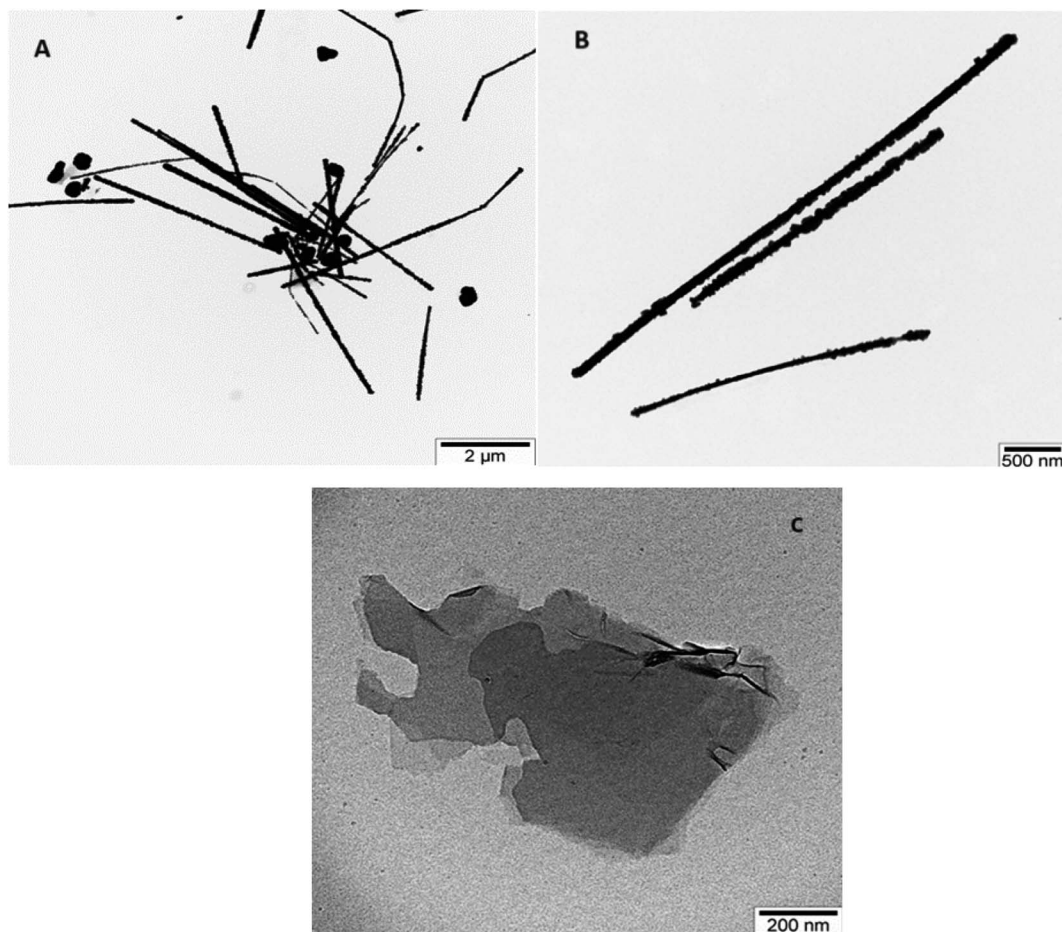


Fig. 5 TEM images of AgNWs (A) and (B) and GO samples (C).

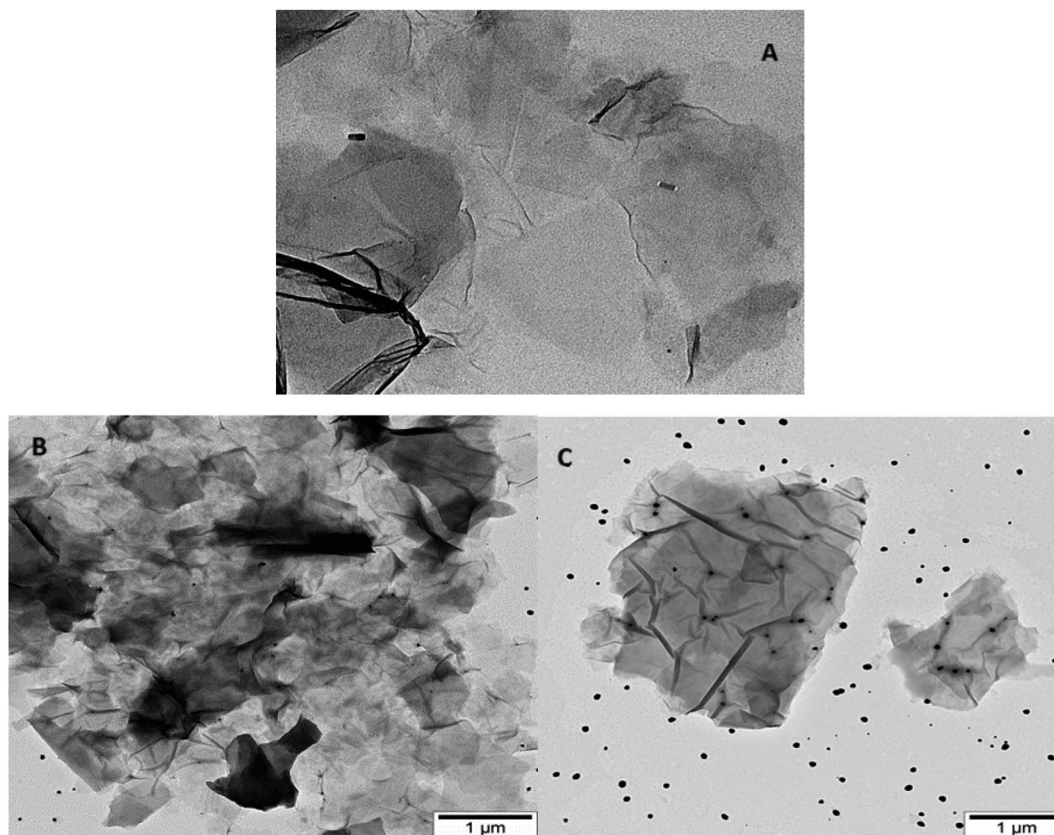


Fig. 6 TEM images of GO/AgNWs (A) and GO/AgNWs + H₂S samples (B) and (C).

GO/AgNWs composites, this value increases to $E_g = 2.43$ eV. This observed increment is attributed to the heightened inter-sheet distance resulting from the introduction of AgNWs between the GO sheets. However, for the GO/AgNWs + H₂S samples, a band gap of $E_g = 2.10$ eV is evident. This phenomenon is ascribed to the formation of Ag₂S nanoparticles due to the sulfidation of AgNWs, the disintegration of GO sheets resulting from sulfidation, and the confinement of electrons from 2D to 3D space. Additionally, the homogeneous distribution of Ag₂S nanocrystals contributes to this effect. According to existing literature, the band gap for Ag₂S nanocrystals falls within the range of $E_g = 0.9$ – 1.1 eV.⁴⁶ Consequently, the analysis of the results indicates that the introduction of sulfur (S) can induce alterations in the band gap of GO/AgNWs composites.

$$\alpha h\nu = \beta(h\nu - E_g)^n \quad (3)$$

$h\nu$ is the photon energy, β is a constant that depends on the structure of the sample and type, E_g is the band gap, the value of n depends on the nature of transition: $n = 2$ for indirect allowed transition and $n = 1/2$ for direct allowed transition, α is the absorption coefficient, its value is obtained from the Beer-Lambert formula.

3.4 TEM analysis

TEM images illustrating AgNWs synthesized through the modified polyol method are presented in Fig. 5A and B. These

images depict variations in the lengths and thicknesses of the produced AgNWs. Measurements reveal nanowire diameters ranging from 110 to 50 nm, with lengths varying between 5 and 2.7 μm . Fig. 5A illustrates the synthesis process, indicating the formation of both nanowires and nanoparticles. Furthermore, the surface of the synthesized AgNWs exhibits a rough texture, with areas featuring small diameters. Additionally, the TEM images highlight that the surfaces are not entirely flat; irregularities such as bends are present along the length of the nanowires.

Fig. 5C present TEM images aimed at elucidating the morphology of GO nanolayers. Notably, the edges of the nanolayers appear transparent, while the color darkens towards the center, suggesting a multilayered structure for the synthesized samples. The dimensions of the GO nanolayers fall within the range of 0.7 to 2 μm .

TEM images of GO/AgNWs composites are illustrated in Fig. 6A. TEM results show that the nanoparticles underwent fragmentation, resulting in fragmented AgNWs ranging in length from 40 to 60 nm. This fragmentation is because of ultrasonic waves during sonication and leads to special examination points. Fig. 6B and C present TEM images of GO/AgNWs composites after exposure to H₂S gas. In Fig. 6B, the GO nanolayers were subjected to decomposition and assembly into a 3D structure under the influence of H₂S gas. Additionally, the AgNWs were partially decomposed, resulting in the formation of Ag₂S nanocrystals (Fig. 6C). It is believed that the sulfur



atoms reacted with the surfaces of the nanoparticles, causing the bonds to break at specific examination points. The size of Ag₂S nanocrystals within the composite ranges from 20 to 60 nm and exhibits a uniform distribution throughout the composites.

4 Conclusion

In this investigation, graphene oxide (GO) was synthesized using a modified Hummers' method, while silver nanowires (AgNWs) were synthesized employing a modified Polyol method. Subsequently, a composite material of GO and AgNWs was prepared through a solvent mixing method. Sulfidation of this composite was achieved through exposure to hydrogen sulfide gas resulting from chemical reactions. Structural analysis results indicate that AgNWs underwent sulfidation during this process, leading to the formation of Ag₂S nanocrystals. TEM results demonstrate that exposure to H₂S gas caused the disintegration and subsequent reassembly of the GO layers. Simultaneously, AgNWs underwent decomposition, forming Ag₂S nanoparticles and achieving a homogeneous distribution between the layers. Moreover, the peak corresponding to the bond between Ag and S in the FTIR spectrum confirms the successful sulfidation process. Additionally, as inferred from the UV-Vis spectroscopy results, the reduction of the composite's band gap to $E_g = 2.10$ eV can be attributed to the reassembly of GO layers and the formation of Ag₂S nanocrystals.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This article partially refunded by European Cooperation in Science and Technology (COST) actions: CA21148 (Research and International Networking on Emerging Inorganic Chalcogenides for Photovoltaics (RENEW-PV)) and CA19118 (High-performance Carbon-based composites with Smart properties for Advanced Sensing Applications (EsSENce)). I am grateful to the anonymous reviewers for their valuable comments and suggestions that helped improve the quality of this paper.

References

- 1 T. Yumura and A. Yamasaki, *Phys. Chem. Chem. Phys.*, 2014, **16**(20), 9656–9666.
- 2 H. Wadhwa, G. Kandhol, U. P. Deshpande, S. Mahendia and S. Kumar, *Colloid Polym. Sci.*, 2020, **298**(10), 1319–1333.
- 3 M. A. Park, S. J. Sung, Y. J. Ahn, I. Hong, I. J. Park, C. R. Park and J. Y. Kim, *ACS Appl. Energy Mater.*, 2021, **4**(9), 8824–8831.
- 4 L. Zhang, W. Zhu, Y. Huang and S. Qi, *Nanomaterials*, 2019, **9**(9), 1264.
- 5 H. S. Kim, M. Patel, H. H. Park, A. Ray, C. Jeong and J. Kim, *ACS Appl. Mater. Interfaces*, 2016, **8**(13), 8662–8669.
- 6 P. Aspermaier, V. Mishyn, J. Binterger, H. Happy, K. Bagga, P. Subramanian, W. Knoll, R. Boukherroub and S. Szunerits, *Anal. Bioanal. Chem.*, 2021, **413**, 779–787.
- 7 J. Wang, M. Yi, Y. Xin, Y. Pang and Y. Zou, *ACS Appl. Mater. Interfaces*, 2021, **14**(43), 48976–48985.
- 8 E. Widiyanto, E. S. Rosa, K. Triyana, N. M. Nursam and I. Santoso, *Adv. Nat. Sci.: Nanosci. Nanotechnol.*, 2021, **12**, 035001.
- 9 K. Y. Yong, Y. K. Chan, E. V. Lau and Y. M. Hung, *Case Stud. Therm. Eng.*, 2022, **31**, 101795.
- 10 K. Gong, J. Hu, N. Cui, Y. Xue, L. Li, G. Long and S. Lin, *Mater. Des.*, 2021, **211**, 110170.
- 11 C. J. Cheng, R. Balamurugan and B. T. Liu, *Micromachines*, 2019, **10**(10), 682.
- 12 L. Badrinezhad, Ç. Bilkan, Y. Azizian-Kalandaragh, A. Nematollahzadeh, I. Orak and S. Altindal, *Int. J. Mod. Phys. B*, 2018, **32**, 1750276.
- 13 K. Jong Min, S. Sang Woo, S. Dong Hee, L. Ha Seung, K. Ju Hwan, J. Chan Wook, K. Sung and C. Suk-Ho, *Curr. Appl. Phys.*, 2017, S1567173917301402.
- 14 G. Zeng, W. Chen, X. Chen, Y. Hu, Y. Chen, B. Zhang and Y. Li, *J. Am. Chem. Soc.*, 2022, **144**(19), 8658–8668.
- 15 C. T. Chou and F. H. Wang, *J. Vac. Sci. Technol. A*, 2018, **36**(5), 05G504.
- 16 F. Duan, W. Li, G. Wang, C. Weng, H. Jin, H. Zhang and Z. Zhang, *Nano Res.*, 2019, **12**, 1571–1577.
- 17 J. Singh and A. S. Dhaliwal, *J. Phys. Chem. Solids*, 2022, **160**, 110358.
- 18 Z. Luo, Z. Cai, Y. Wang, Y. Wang and B. Wang, *RSC Adv.*, 2016, **6**(43), 37124–37129.
- 19 B. M. Al-Shehri, M. Shkir, T. M. Bawazeer, S. AlFaify and M. S. Hamdy, *Phys. E*, 2020, **121**, 114060.
- 20 P. Storme, O. Schalm and R. Wiesinger, *Heritage Sci.*, 2015, **3**(1), 1–15.
- 21 V. J. Keast, *Corros. Mater. Degrad.*, 2022, **3**(2), 221–234.
- 22 Y. Zhang, K. Wang, Y. Yang, J. Xu, B. Sun and L. Zhu, *Ecotoxicol. Environ. Saf.*, 2019, **185**, 109739.
- 23 N. H. A. Rosli, K. S. Lau, T. Winie, S. X. Chin and C. H. Chia, *Diamond Relat. Mater.*, 2021, **120**, 108696.
- 24 Y. Zhao, C. Zhang, T. Liu, R. Fan, Y. Sun, H. Tao and J. Xue, *Int. J. Electrochem. Sci.*, 2017, **12**(4), 3537–3548.
- 25 Z. Tian, J. Li, G. Zhu, J. Lu, Y. Wang, Z. Shi and C. Xu, *Phys. Chem. Chem. Phys.*, 2016, **18**(2), 1125–1130.
- 26 Y. Wang, M. Hu, D. Ai, H. Zhang, Z. H. Huang, R. Lv and F. Kang, *Nanomaterials*, 2019, **9**(5), 752.
- 27 J. Wu, T. Deng, Q. Wu, Y. Qiu, Y. Wei, Q. Zhao and Y. Zhang, *Appl. Mater. Today*, 2023, **32**, 101826.
- 28 S. Pan, X. Liu and X. Wang, *Mater. Charact.*, 2011, **62**(11), 1094–1101.
- 29 A. U. Khan, A. Arooj, K. Tahir, M. M. Ibrahim, V. Jevtovic, H. A. AL-Abdulkarim, E. A. Saleh, H. S. Al-Shehri, M. A. Amin and B. Li, *J. Mol. Struct.*, 2022, **1251**, 131991.
- 30 A. Badawi, N. Y. Mostafa, N. M. Al-Hosiny, A. Merazga, A. M. Albaradi, F. Abdel-Wahab and A. A. Atta, *Mod. Phys. Lett. B*, 2018, **32**(16), 1850172.
- 31 L. Velasco Davoise, A. M. Díez-Pascual and R. Peña Capilla, *Materials*, 2022, **15**(3), 1171.



- 32 X. Wu, Y. Xie, C. Xue, K. Chen, X. Yang and L. Xu, *Mater. Res. Express*, 2019, **6**(7), 075306.
- 33 E. Sujiono, H. Zurnansyah, D. Zabrian, M. Y. Dahlan, B. D. Amin and J. Samnur Agus, *Heliyon*, 2020, **6**(8), 04568.
- 34 M. J. Yoo and H. B. Park, *Carbon*, 2019, **141**, 515–522.
- 35 S. Fahad, L. Wang, J. Liu, S. Li, J. Fu, B. U. Amin, R. U. Khan, S. Mehmood, F. Haq, W. Nan and M. Usman, *Mater. Chem. Phys.*, 2021, **267**, 124643.
- 36 M. Muradov, M. B. Baghirov, G. Eyvazova, L. Gahramanli, S. Mammadyarova, G. Aliyeva and M. Abdullayev, *Radiat. Phys. Chem.*, 2023, **208**, 110926.
- 37 J. Lu, D. Liu and J. Dai, *J. Mater. Sci.: Mater. Electron.*, 2019, **30**(16), 15786–15794.
- 38 I. O. Faniyi, O. Fasakin, B. Olofinjana, A. S. Adekunle, T. V. Oluwasusi, M. A. Eleruja and E. O. B. Ajayi, *SN Appl. Sci.*, 2019, **1**, 1–7.
- 39 S. Gurunathan, J. Hyun Park, Y. J. Choi, J. Woong Han and J. H. Kim, *Curr. Nanosci.*, 2016, **12**(6), 762–773.
- 40 K. Jyoti, M. Baunthiyal and A. Singh, *J. Radiat. Res. Appl. Sci.*, 2016, **9**(3), 217–227.
- 41 S. Fahad, H. Yu, L. Wang, A. Nazir, R. S. Ullah, K. U. R. Naveed and S. Mehmood, *J. Mater. Sci.: Mater. Electron.*, 2019, **30**, 12876–12887.
- 42 S. Banerjee, B. Show, A. Kundu, J. Ganguly, U. Gangopadhyay, H. Saha and N. Mukherjee, *J. Ind. Eng. Chem.*, 2016, **40**, 54–61.
- 43 Y. Ma, Y. Ye, H. Wan, L. Chen, H. Zhou and J. Chen, *Tribol. Lett.*, 2019, **67**, 1–11.
- 44 N. M. S. Hidayah, *et al.*, *AIP Conference Proceedings*, AIP Publishing, 2017, vol. 1892, 1.
- 45 Y. Jiang, Y. Lu, D. Han, Q. Zhang and L. Niu, *Nanotechnology*, 2012, **23**(10), 105609.
- 46 R. Zamiri, H. Abbastabar Ahangar, A. Zakaria, G. Zamiri, M. Shabani, B. Singh and J. M. F. Ferreira, *Chem. Cent. J.*, 2015, **9**(1), 1–6.

